



**THE DATASHEET OF  
MBR20100CTG**



# MBR2080CTG, MBR2090CTG, MBR20100CTG

## Switch-mode Power Rectifiers

This series uses the Schottky Barrier principle with a platinum barrier metal. These state-of-the-art devices have the following features:

### Features

- 20 A Total (10 A Per Diode Leg)
- Guard-Ring for Stress Protection
- Low Forward Voltage
- 175°C Operating Junction Temperature
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Low Power Loss/High Efficiency
- High Surge Capacity
- Low Stored Charge Majority Carrier Conduction
- Shipped 50 units per plastic tube
- These Devices are Pb-Free and are RoHS Compliant\*

### Mechanical Characteristics:

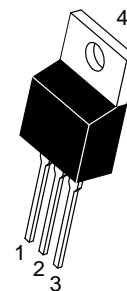
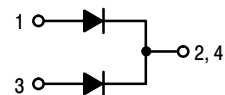
- Case: Epoxy, Molded
- Weight: 1.9 grams (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes:  
260°C Max. for 10 Seconds



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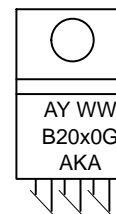
[www.onsemi.com](http://www.onsemi.com)

## SCHOTTKY BARRIER RECTIFIERS 20 AMPERES 80–100 VOLTS



TO-220  
CASE 221A  
STYLE 6

### MARKING DIAGRAM



A = Assembly Location  
Y = Year  
WW = Work Week  
B20x0 = Device Code  
x = 8, 9 or 10  
G = Pb-Free Device  
AKA = Polarity Designator

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

**ORDERING INFORMATION**  
See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

# MBR2080CTG, MBR2090CTG, MBR20100CTG

## MAXIMUM RATINGS (Per Diode Leg)

Rating	Symbol	MBR			Unit
		2080CT	2090CT	20100CT	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$V_{RRM}$ $V_{RWM}$ $V_R$	80	90	100	V
Average Rectified Forward Current (Rated $V_R$ ) $T_C = 133^\circ\text{C}$	$I_{F(AV)}$	10			A
Peak Repetitive Forward Current (Rated $V_R$ , Square Wave, 20 kHz) $T_C = 133^\circ\text{C}$	$I_{FRM}$	20			A
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	$I_{FSM}$	150			A
Peak Repetitive Reverse Surge Current (2.0 $\mu\text{s}$ , 1.0 kHz)	$I_{RRM}$	0.5			A
Operating Junction Temperature (Note 1)	$T_J$	-65 to +175			$^\circ\text{C}$
Storage Temperature	$T_{stg}$	-65 to +175			$^\circ\text{C}$
Voltage Rate of Change (Rated $V_R$ )	$dv/dt$	10,000			V/ $\mu\text{s}$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. The heat generated must be less than the thermal conductivity from Junction-to-Ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ .

## THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Maximum Thermal Resistance Junction-to-Case	$R_{\theta JC}$	2.0	$^\circ\text{C/W}$
Junction-to-Ambient	$R_{\theta JA}$	60	

## ELECTRICAL CHARACTERISTICS (Per Diode Leg)

Characteristic	Symbol	Value	Unit
Maximum Instantaneous Forward Voltage (Note 2) ( $i_F = 10$ Amps, $T_C = 125^\circ\text{C}$ ) ( $i_F = 10$ Amps, $T_C = 25^\circ\text{C}$ ) ( $i_F = 20$ Amps, $T_C = 125^\circ\text{C}$ ) ( $i_F = 20$ Amps, $T_C = 25^\circ\text{C}$ )	$V_F$	0.75 0.85 0.85 0.95	V
Maximum Instantaneous Reverse Current (Note 2) (Rated dc Voltage, $T_C = 125^\circ\text{C}$ ) (Rated dc Voltage, $T_C = 25^\circ\text{C}$ )	$i_R$	6.0 0.1	mA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Pulse Test: Pulse Width = 300  $\mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .

## ORDERING INFORMATION

Device	Package	Shipping
MBR2080CTG	TO-220 (Pb-Free)	50 Units / Rail
MBR2090CTG	TO-220 (Pb-Free)	50 Units / Rail
MBR20100CTG	TO-220 (Pb-Free)	50 Units / Rail

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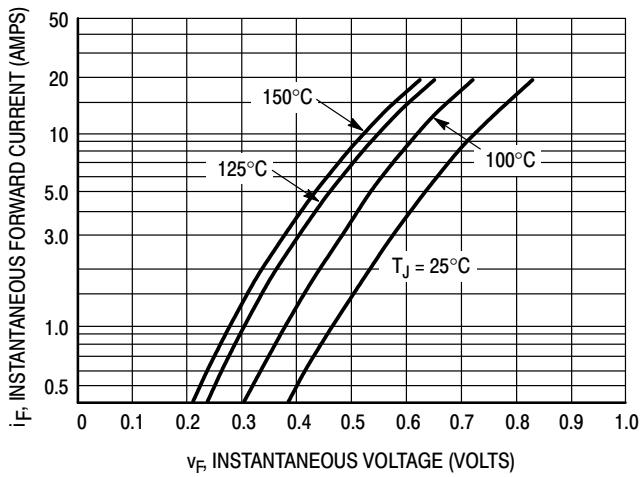


Figure 1. Typical Forward Voltage Per Diode

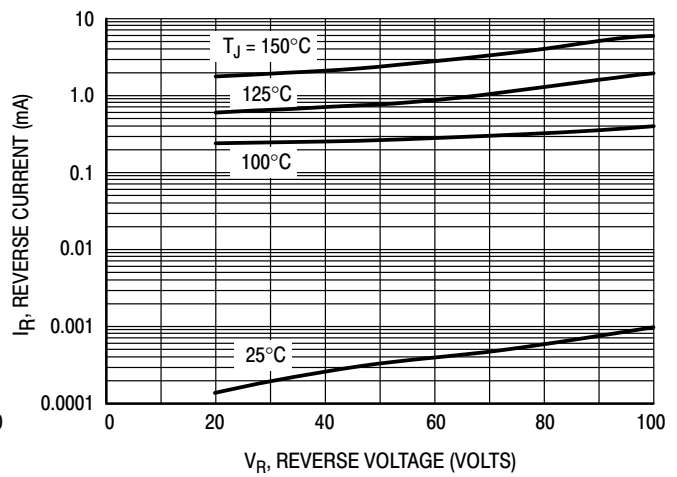


Figure 2. Typical Reverse Current Per Diode

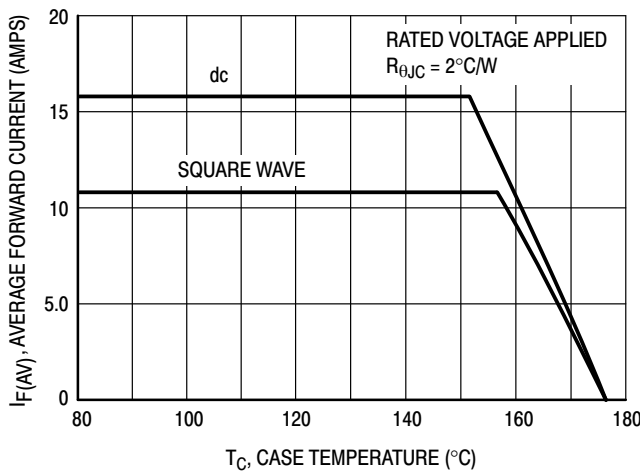


Figure 3. Typical Current Derating, Case, Per Leg

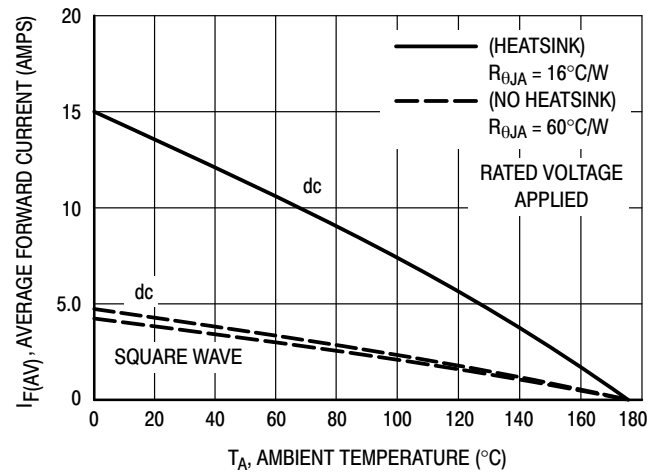


Figure 4. Typical Current Derating, Ambient, Per Leg

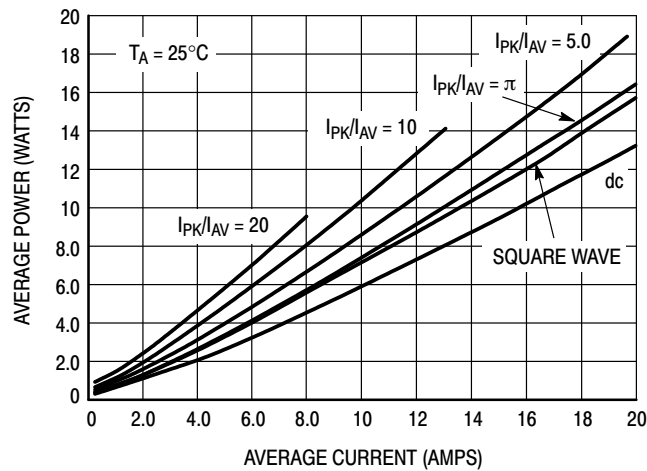


Figure 5. Average Power Dissipation and Average Current

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